

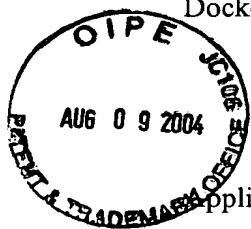
08-11-04

IFW

Express Mailing Label No. EV 380181639 US

Docket No. P0370US-7

PATENT



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: MACKAMURA et al.

Serial No. 10/848,937

Art Unit: 2828

Filing Date: May 18, 2004

For: METHOD FOR FABRICATING THIN FILM SEMICONDUCTOR DEVICES AND DEVICES FABRICATED USING METHOD (changed herein to METHOD FOR FABRICATING GROUP-III NITRIDE DEVICES AND DEVICES FABRICATED USING MEHTOD)

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

PRELIMINARY AMENDMENT TRANSMITTAL


Sir:

Transmitted herewith is a Preliminary Amendment for this application. Applicant is a large entity.

If any additional fee is required, charge Account No. 11-1580. A duplicate of this transmittal is attached.

Respectfully submitted,

August 9, 2004



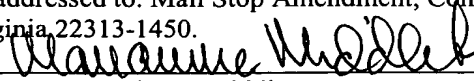
Jaye G. Heybl
Registration No. 42,661
Attorney for Applicant

KOPPEL, JACOBS, PATRICK & HEYBL
555 St. Charles Drive, Suite 107
Thousand Oaks, California, 91360
Telephone: (805) 373-0060

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service via Express mail in an envelope addressed to: Mail Stop Amendment, Commissioner of Patents, P.O. Box 1450, Alexandria, Virginia 22313-1450.

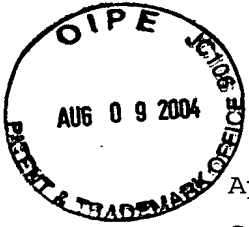
8/9/04
Date



Marianne Middleton

Docket No. P0370US-7

PATENT



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Mackamura et al.

Serial No. 10/848,937

Art Unit: 2828

Filed: May 18, 2004

Title: METHOD FOR FABRICATING THIN FILM SEMICONDUCTOR
DEVICES AND DEVICES FABRICATED USING METHOD (changed herein
to METHOD FOR FABRICATING GROUP-III NITRIDE DEVICES AND
DEVICES FABRICATED USING METHOD)

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

PRELIMINARY AMENDMENT

Sir:

Applicant hereby submits the following Preliminary
Amendment:

Amendments to the Specification begin on page 2 of this
paper.

A Listing of the Claims is shown beginning on page 3 of this
paper.

Remarks begin on page 12 of this paper.